

TN6707A

NPN General Purpose Amplifier

- These devices is designed for general purpose medium power amplifiers and switches requiring collector currents to 1.0A
- · Sourced from process 39.



Absolute Maximum Ratings* T_A=25°C unless otherwise noted

Symbol	Parameter	FPN660	Units
V _{CEO}	Collector-Emitter Voltage	80	V
V _{CBO}	Collector-Base Voltage	100	V
V _{EBO}	Emitter-Base Voltage	5.0	V
I _C	Collector Current - Continuous	1.2	Α
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 ~ +150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- These ratings are based on a maximum junction temperature of 150°C.
 These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics TA=25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Max.	Units	
Off Chara	Off Characteristics					
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage *	I _C = 10mA, I _B = 0	80		V	
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_E = 100 \mu A, I_E = 0$	100		V	
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 1.0mA, I _C = 0	5.0		V	
I _{CBO}	Collector-Base Cutoff Current	V _{CB} = 80V, I _E = 0		0.1	μΑ	
I _{EBO}	Emitter-Base Cutoff Current	V _{EB} = 5.0V, I _C = 0		0.1	μΑ	
On Characteristics *						
h _{FE}	DC Current Gain	V _{CE} = 2.0V, I _C = 50mA	40			
		$V_{CE} = 2.0V, I_{C} = 250mA$	40	250		
		$V_{CE} = 2.0V, I_{C} = 500mA$	25			
V _{CF} (sat)	Collector-Emitter Saturation Voltage	I _C = 500mA, I _B = 50mA		0.5	V	
02.		I _C = 1.0A, I _B = 100mA		1.0	V	
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} = 2.0V, I _C = 1.0A		1.5	V	
Small Signal Characteristics						
h _{fe}	Output Capacitance	V _{CE} = 5.0V, I _C = 200mA, f = 20MHz	2.5	20	MHz	
f _T	Current Gain Bandwidth Product	V _{CE} = 5.0V, I _C = 50mA, f = 20MHz	50		MHz	
Pulsa Tast: Pulsa Width < 300us Puty Cycle < 2.0%						

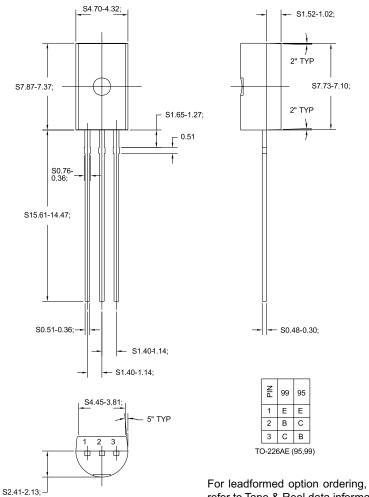
Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2.0%

Thermal Characteristics T_A=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
P _D Total Device Dissipation		1.0	W
	Derate above 25°C	8.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	50	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	125	°C/W

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refer to Tape & Reel data information.

Dimensions in Millimeters

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